

3. High-D Consortium Meeting

Wednesday 21 February 2024

Radiation effects (02:20 - 04:00)

time	[id] title	presenter
02:20	[68] Investigation of high resistivity p-type FZ silicon diodes after 60Co - □ irradiation	LIAO, Chuan
02:40	[71] Latest results from irradiated DPTS sensors produced in 65 nm CMOS technology	BECHT, Pascal
03:00	[72] Radiation tolerance of the MIMOSIS-1 CMOS sensor	DEVEAUX, Michael
03:20	[67] Study of the self-heating in SiPMs	VILLALBA PETRO, Carmen Victoria